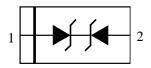


Description

The PESDHC2FD5VBH protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



Feature

- 300W peak pulse power per line ($t_P = 8/20\mu s$)
- DFN1006-2L package
- Replacement for MLV(0402)
- Bidirectional configurations
- Response time is typically < 1ns
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to

IEC61000-4-2(ESD) ±30KV(air), ±30KV(contact);

IEC61000-4-4 (EFT) 40A (5/50ns)

IEC61000-4-5 (Surge) 36A (8/20us)

Applications

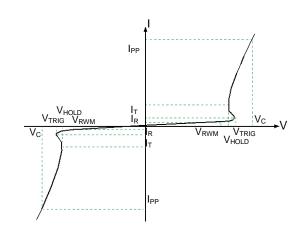
- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Pure tin plating: 7 ~ 17 um
- Pin flatness:≤3mil

Electronics Parameter

Symbol	Parameter		
V_{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V_{TRIG}	Reverse trigger Current		
V _{HOLD}	Reverse holding voltage		
I _T	Test Current		
I _{PP}	Maximum Reverse Peak Pulse Current		
V _C	Clamping Voltage @ I _{PP}		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
I _F	Forward Current		
V _F	Forward Voltage @ I _F		



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage(PIN1~PIN2)	V_{RWM}				5	V
Breakdown Voltage(PIN1~PIN2)	V_{BR}	I _t =1mA	5.4		6.5	V
Reverse Leakage Current(PIN1~PIN2)	I _R	V _{RWM} = 5V T=25°C			1.0	μΑ
Breakdown Voltage (PIN2~PIN1)	V_{BR}	I _t =1mA	4.6		5.5	V
Reverse Leakage Current(PIN2~PIN1)	I _R	V _{RWM} = 4.5V T=25℃			1.0	μΑ
Clamping Voltage(PIN1~PIN2)	V _C	I _{PP} =1A		6	8	V
Clamping Voltage(PIN1~PIN2)	Vc	I _{PP} =15A		7.2	9	V
Clamping Voltage(PIN1~PIN2)	Vc	I _{PP} =33A		9.5	11	V
Junction Capacitance	C _j	V _R =0V f = 1MHz	70	80	90	pF

Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20µs)	P _{pp}	300	W
Operating Temperature	TJ	-55 to +150	$^{\circ}\! \mathbb{C}$
Storage Temperature	T _{STG}	-55 to +150	$^{\circ}$

Typical Characteristics



Fig 1.Pulse Waveform

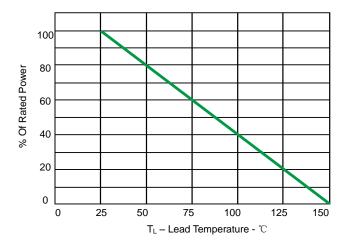


Fig 2.Power Derating Curve

20

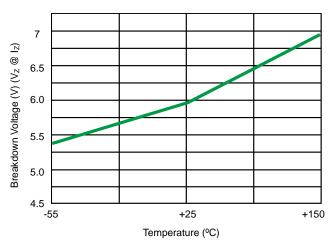


Fig 3.Typical Breakdown Voltage vs. Temperature

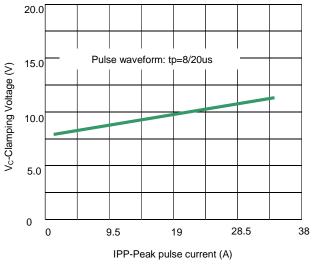
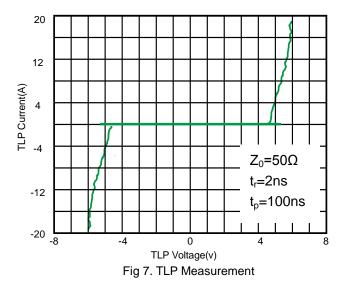


Fig 5. Clamping voltage vs. Peak pulse current



16 12 8 4 0 0 25 50 75 100 125 150 Temperature (°C)

Fig 4.Typical Leakage Current vs. Temperature

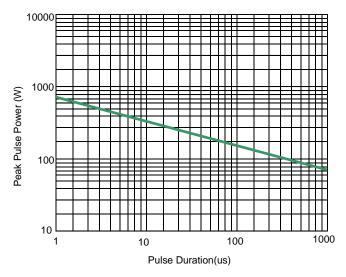
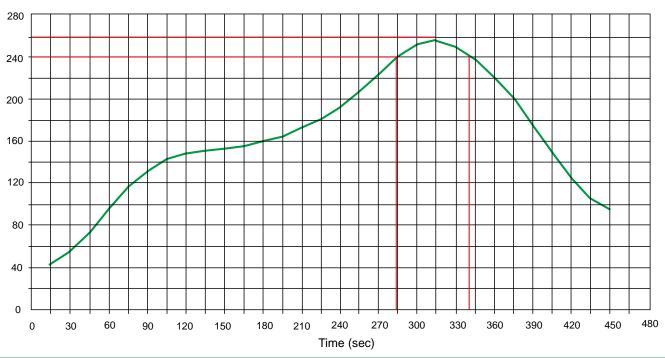


Fig 6. Non-Repetitive Peak Pulse Power vs. Pulse time

Solder Reflow Recommendation

Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

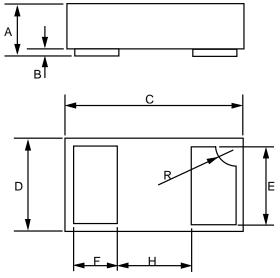


PCB Design

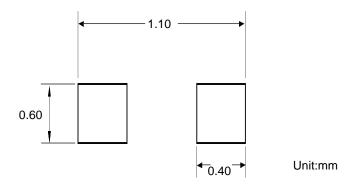
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

Product dimension (DFN1006-2L)



Dim	Inc	hes	Millimeters		
DIM	MIN	MAX	MIN	MAX	
Α	0.013	0.020	0.34	0.50	
В	0.000	0.002	0.00	0.05	
С	0.037	0.042	0.95	1.075	
D	0.021	0.026	0.55	0.675	
Е	0.017	0.021	0.45	0.55	
F	0.007	0.011	0.20	0.30	
Н	0.015Тур.		0.40	Тур.	
R	0.001	0.005	0.05	0.15	



Ordering information

Device	Package	Shipping
PESDHC2FD5VBH	DFN1006-2L (Pb-Free)	10000 / Tape & Reel

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